# • PATENT APPLICATION

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FORM PTO-1449	ATTY. DKT NO.	01-493	SER. NO.
	APPLICANT	FUKUDA et al.	
	FILING DATE	October 21, 2003	GROUP

### REFERENCE DESIGNATION

spec.)

### **U.S. PATENT DOCUMENTS**

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS
TOU	4,636,825	Jan. 13, 1987	Baynes		
TN	4,948,754	Aug. 14, 1990	Kondo et al.		
177/	5,192,989	Mar. 9, 1993	Matsushita et al.		
MET	5,412,239	May 2, 1995	Williams		
	5,672,894	Sep. 30. 1997	Maeda et al.		

#### FOREIGN PATENT DOCUMENTS

TRANSLATION SUB DOCUMENT NUMBER DATE COUNTRY NAME CLASS YES NO CLASS JP-A-H07-263665 Х 10/13/95 **JAPAN** (Discussed in page 1 of the (Abstract) JP-A-H03-239369 10/24/91 **JAPAN** (Abstract)

\* Full English text of the JP Document will be available in machine-translated form from JP (Japanese Patent Office) English language web site at http://www1.ipdl.jpo.go.jp/PA1/cgi-bin/PA1INDEX.

## OTHER REFERENCES (including Author, Title, Date, Pertinent Pages, etc.)

WIT		Hazel Schofield et al., "Assembly of FlipFET™ Devices", International Rectifier, AN-1011, 5/22/2000, pp.1-6
MACT		"International Rectifier", IRF6150, PD-93943, pp. 1-3
MI	/	Hazel Schofield et al., "FlipFETTM MOSFET Design for High Volume SMT Assembly", International Rectifier, pp.1-6
EXAMINER	> /	DATE CONSIDERED
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